



MR3029-81

JFW

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Shangir Gwo :  
Serial No. : 10/714,649 : Art Unit #2818  
Filed : 18 November 2003 : Examiner: D. A. Le  
Title : METHOD FOR GROWING GROUP-III  
NITRIDE SEMICONDUCTOR  
HETEROSTRUCTURE ON SILICON  
SUBSTRATE

RESPONSE TO RESTRICTION REQUIREMENT  
AND AMENDMENT

Mail Stop NO FEE  
Honorable Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Sir:

Applicant, by the undersigned attorney hereby responds to the outstanding  
Official Action dated 9 March 2005 which is a Restriction Requirement. Please  
amend the above-referenced patent application as follows:

**Amendments to the Claims** begin on page 2 of this paper.

**Remarks/Arguments** begin on page 8 of this paper.